

# ISOCOM<sup>®</sup>



Hutton Close, Crowther Ind Est, Washington, Tyne & Wear NE38 0AH, England  
[Email: enquiry@isocomoptocouplers.com](mailto:enquiry@isocomoptocouplers.com) - Tel: +44 (0)191 4166546 - Fax: +44 (0)191 4155055

## CNG35, CNG36, CNG39 CNX35, CNX36, CNX39 OPTICALLY COUPLED ISOLATORS

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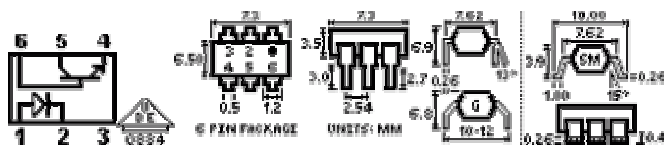
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### Circuit



### Features

- 3120-4400 Volt Isolation.
- High DC Current Transfer Ratio.
- Low Cost Dual-In-Line Package.
- Working Voltage 2500 VDC

### Description

The CNG/CNX Series are optically coupled isolators consisting of a Gallium Arsenide infrared emitting diode and an NPN silicon phototransistor mounted in a standard 6-pin dual-in-line package. Surface Mount Option Available.

All electrical parameters are 100% tested by manufacturing. Specifications are guaranteed to a cumulative 0.65% AQL

## Absolute Maximum Ratings (Ta=25°C)

Storage Temperature:	-55°C to +150°C
Operating Temperature:	-55°C to +100°C
Lead Soldering:	260°C for 10s, 1.6mm from case
Input-To-Output Isolation Voltage:	3120-4400Vdc

## Input Diode

Forward DC Current:	100mA
Reverse DC Voltage:	5V
Peak Forward Current (1µs p.w. 300pps):	3A
Power Dissipation:	200mW
Derate Linearly:	1.33mW/°C above 25°C

## Output Transistor

Collector-Emitter Voltage:	30V
Power Dissipation:	200mW

## Optocoupler

Collector Cut-off Current (Dark) $I_{CEW}$ :	200nA Max (Vcc=10V; work. volt.=2.5kV Diode;
Isolation Voltage DC $V_{IO}$ :	If=0)
Isolation Voltage AC (RMS) $V_{IO}$ :	4.4kVMin
	3.12kVMin

## Package

Total Power Dissipation:	250mW
Derate Linearly:	3.3mW/°C above 25°C

## Electro-optical Characteristics (Ta=25°C)

INPUT	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
$V_F$	Forward Voltage	$I_F=10mA$			1.5	V
$I_R$	Reverse Current	$V_R=5V$			10	µA
OUTPUT	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
$I_{CEO}$	Collector cut-off current (dark)	$V_{CE}=10V$			50	nA
		$V_{CE}=10V, T_A=70°C$			10	µA
		$V_{CB}=10V$			20	nA
	Collector-Emitter Breakdown	$V_{(BR) CEO}$	30			V

	Voltage					
<b>COUPLED</b>	<b>PARAMETER</b>	<b>CONDITIONS</b>	<b>MIN</b>	<b>TYP</b>	<b>MAX</b>	<b>UNIT</b>
I <sub>C</sub> /I <sub>F</sub>	DC Current Transfer Ratio					
	CNG/CNX35	I <sub>F</sub> =10mA, V <sub>CE</sub> =5V	40		80	%
	CNG/CNX36		63		125	%
	CNG/CNX39		100		200	%
R <sub>IO</sub>	Input-to-Output Isolation Resistance	V <sub>IO</sub> =500V, (note 1)	100			Gohm
V <sub>CE(SAT)</sub>	Collector-Emitter Saturation Voltage	I <sub>F</sub> =10mA, I <sub>C</sub> =2.5mA		0.2	0.4	V
C <sub>IO</sub>	Capacitance Input to Output	f=1MHz (note 1)		0.6		pf
T <sub>R</sub>	Output Rise Time	I <sub>F</sub> =10mA, V <sub>CC</sub> =5.0V		2	4	μs
T <sub>ON</sub>	Output Turn-on Time	R <sub>L</sub> =75ohm, T <sub>A</sub> =25°C		3	5.6	μs
T <sub>F</sub>	Output Fall Time			2	3.5	μs
T <sub>OFF</sub>	Output Turn-off Time			2.5	4.1	μs

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